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## LITHOGRAPHY TRACK SYSTEM

#### Abstract

A lithography track system includes a plurality of process modules each configured to perform a photolithography process on a wafer, a transfer module configured to transfer the wafer between the plurality of process modules, a scanner at one end of the transfer module and configured to expose a photoresist material on the wafer, and a first interface box sharing the transfer module and configured to transfer the wafer to the scanner and to match vacuum degrees of the transfer module and the scanner.

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# **Background/Summary**

## CROSS-REFERENCE TO RELATED APPLICATION(S)

[0001] This application claims benefit of priority to Korean Patent Application No. 10-2024-0021764, filed on Feb. 15, 2024 in the Korean Intellectual Property Office, the disclosure of which is incorporated herein by reference in its entirety.

#### BACKGROUND

[0002] The present inventive concept relates to a lithography track system.

[0003] The manufacturing of semiconductor devices, such as integrated circuits, is a multi-step process including a photolithography process.

[0004] Generally, a semiconductor manufacturing process includes depositing a material on a wafer and patterning the material through lithographic techniques to form structural features (e.g., transistors and circuits) of semiconductor devices.

[0005] The lithography process includes applying photoresist on a semiconductor wafer (i.e., performing spin-coating); exposing the applied photoresist with a scanner; baking the exposed wafer; performing developing with a developing solution to remove an exposed region of the photoresist on the wafer; and performing additional processing, such as etching or material deposition, cleaning, and the like.

[0006] As patterns on semiconductor chips have become more refined, a dry photoresist process of using dry photoresist and performing a dry developing process, rather than using wet photoresist or wet developing solution, and equipment suitable therefor is under development.

[0007] In addition, an all-in-one track system in which all processes are integrated and automated to ensure mass production and productivity of semiconductor chips has been introduced. Although an all-in-one system for a dry photo process has been developed, a scanner device for exposure is configured as a stand-alone device that is not connected in-line, and thus, a problem arises in that a wafer movement process should be operated independently between an all-in-one track and a scanner.

[0008] There is also a problem that a wafer can be contaminated by metal reaction by-products in the scanner and a front opening unified pod (FOUP) and a transfer module are contaminated due to metal outgassing.

[0009] Independent stand-alone scanners have various process delays, such as post-coating delay (PCD), post exposure delay (PED), and post exposure bake (PEB) delay, post dry develop delay (PDDD) is caused, which causes a problem that a critical dimension (CD) is drifted and is also accompanied by a problem of productivity deterioration.

#### **SUMMARY**

[0010] An aspect of the present inventive concept is to provide a lithography track system in which a scanner is in-line in a track system that continuously performs a dry photolithography process. [0011] An aspect of the present inventive concept is to provide a lithography track system including an interface box of transferring a wafer under normal pressure that has undergone a dry photo process in an in-line lithography track system to a scanner in a vacuum state through a wafer transporter of a track.

[0012] An aspect of the present inventive concept is to provide a lithography track system installed at the entrance of a processing chamber and including an interface box of transferring a wafer under normal pressure to a processing chamber under vacuum through a wafer transporter of a track.

[0013] According to an aspect of the present inventive concept, a lithography track system includes a plurality of process modules each configured to perform a photolithography process on a wafer, a transfer module configured to transfer the wafer between the plurality of process modules, a

scanner at one end of the transfer module and configured to expose a photoresist material on the wafer, and a first interface box sharing the transfer module and configured to transfer the wafer to the scanner and to match vacuum degrees or levels of the transfer module and the scanner. [0014] According to an aspect of the present inventive concept, a lithography track system, in which a wafer is sequentially transferred to a plurality of process modules and processed sequentially or simultaneously in the plurality of process modules, includes a transfer module configured to transfer the wafer between the plurality of process modules, wherein the plurality of process modules include a coating process module configured to dry-coat the wafer with photoresist, a scanner configured to expose the coated wafer to electromagnetic radiation, a baking process module configured to dry-bake the coated or exposed wafer, and a dry development module configured to dry-remove the exposed wafer or a pattern thereon, wherein a first interface box configured to match a vacuum degree or level with the scanner is at an introduction side of the scanner.

[0015] According to an aspect of the present inventive concept, a lithography track system includes an equipment front-end module configured to supply a wafer, a plurality of process modules configured to sequentially or simultaneously process the wafer, a transfer module having a first end connected to the equipment front-end module and configured to transfer the wafer, and a second interface box configured to move the wafer to and from the transfer module between at least one of the plurality of process modules and the transfer module.

# **Description**

#### BRIEF DESCRIPTION OF DRAWINGS

[0016] The above and other aspects, features, and advantages of the present inventive concept will be more clearly understood from the following detailed description, taken in conjunction with the accompanying drawings, in which:

- [0017] FIG. **1** is a schematic diagram of a cluster-type lithography track system according to example embodiments of the present inventive concept;
- [0018] FIG. **2** is a schematic diagram of a track-type lithography track system according to example embodiments of the present inventive concept;
- [0019] FIG. **3** is a schematic diagram illustrating portion A of FIG. **1** according to example embodiments of the present inventive concept;
- [0020] FIG. **4** is a schematic diagram illustrating portion A' of FIG. **2** according to example embodiments of the present inventive concept;
- [0021] FIG. **5** is a schematic enlarged view illustrating portion B of FIG. **1** according to example embodiments of the present inventive concept;
- [0022] FIG. **6** is a schematic enlarged view illustrating portion B' of FIG. **2** according to example embodiments of the present inventive concept;
- [0023] FIG. **7** is a schematic enlarged view illustrating portion B' of FIG. **2** according to other example embodiments of the present inventive concept; and
- [0024] FIG. **8** is a schematic diagram illustrating a state in which a wafer is transferred to a process module in a track-type lithography track system according to example embodiments of the present inventive concept.

#### DETAILED DESCRIPTION

[0025] Hereinafter, example embodiments in the present inventive concept will be described in detail with reference to the accompanying drawings.

[0026] The example embodiments of the present inventive concept may be modified into other forms and are provided so that this disclosure will be thorough and complete and will fully convey the scope of the invention to those of ordinary skill in the art. In the drawings, the shapes and

dimensions of elements may be exaggerated for clarity, and like reference numerals denote like elements.

[0027] In the present disclosure, the meaning of a "connection" of a component to another component includes an indirect connection through another element as well as a direct connection between two components. In addition, in some cases, the meaning of "connection" includes all "electrical connections."

[0028] It may be understood that when an element is referred to with "first" and "second", the element is not limited thereby. They may be used only for a purpose of distinguishing the element from the other elements, and may not limit the sequence or importance of the elements. In some cases, a first element may be referred to as a second element without departing from the scope of the claims set forth herein. Similarly, a second element may also be referred to as a first element. [0029] The terms used in the present disclosure are used to describe example embodiments and are not intended to limit the present inventive concept. A singular term includes a plural form unless otherwise indicated.

[0030] FIG. **1** is a schematic diagram of a cluster-type lithography track system according to example embodiments of the present inventive concept, and FIG. **2** is a schematic diagram of a track-type lithography track system according to example embodiments of the present inventive concept.

[0031] Referring to FIGS. **1** and **2**, example embodiments of a lithography track system are disclosed in which a wafer W is sequentially transferred to a plurality of process modules and processed sequentially or simultaneously in the plurality of process modules.

[0032] FIG. **1** illustrates a cluster-type lithography track system in which a robot arm for transferring a wafer W to a process module is installed at the center of a polygonal table. FIG. **2** illustrates a track-type lithography track system in which multi-process modules are arranged on both or opposite sides of a transport module.

[0033] A cluster-type lithography track system **100** of FIG. **1** includes a plurality of process modules **120**, a transfer module **140**, a scanner **150**, and a first interface box **160**.

[0034] The plurality of process modules **120** include process modules **122**, **124**, . . . that perform respective semiconductor processes for a semiconductor photolithography process.

[0035] First, the cluster-type lithography track system **100** includes an equipment front-end module (EFEM) **102** supplying a wafer.

[0036] A photolithography process of the wafer W transferred from the EFEM **102** may be continuously performed in the plurality of process modules **120**.

[0037] The plurality of process modules **120** may include a coating process module, a baking process module, and a dry development module.

[0038] The location or number of each of the process modules **122** and **124** may be arbitrarily changed depending on selection.

[0039] In the coating process module, a photoresist layer is deposited. This may be a dry deposition process, such as a vapor deposition process, or a wet process, such as a spin-on deposition process. [0040] The photoresist may be a metal-containing extreme ultraviolet radiation (EUV) resist. EUV-sensitive metal or metal oxide-containing films may be used for wet (e.g., spin-on) or dry (e.g., chemical vapor deposition (CVD)) techniques.

[0041] In the present example embodiment, a dry photoresist process using dry photoresist and performing a dry developing process may be performed to further refine patterns on a semiconductor chip.

[0042] The fire process module is a process module used to process a post-application bake (PAB) after performing a photoresist deposition and after performing a bevel edge and/or backside cleaning or used to perform post-exposure bake (PEB) or post-development hard bake after EUV exposure.

[0043] The dry development module may be performed in a thermal processing chamber, such as a

baking plate or oven. In some example embodiments, a method of depositing and developing a photoresist may include baking a metal-containing EUV resist at an increased temperature in the same processing chamber as that of dry developing the metal-containing EUV resist.

[0044] The scanner **150** exposes photoresist materials deposited on a semiconductor wafer to some types of electromagnetic radiation (e.g., extreme ultraviolet radiation (EUV)).

[0045] In addition, the process modules **122** and **124** may include a cleaning module of removing contamination from the wafer W. An optional cleaning process may be performed to clean the backside and/or beveled edges of the semiconductor substrate.

[0046] The cluster-type lithography track system **100** includes a transfer module system for transferring the wafer W between the process modules **122** and **124**.

[0047] The transfer module system includes a transfer robot arm **145** for transferring the wafer and a transfer module **140** extending from one side of a polygonal cluster die or table to transfer the wafer W to the scanner **150**.

[0048] The transfer module **140** includes a vacuum transport robot **144** (or a vacuum transport module) for transferring the wafer and a track **142** on which the vacuum transport robot **144** may move.

[0049] The scanner **150** is located at one end of the transfer module **140**, and the wafer is moved to the scanner **150** for an exposure process through the transfer module **140**. The wafer that has completely undergone the exposure process may be transferred from the scanner **150** to the process module **120**.

[0050] The first interface box **160** may share the transfer module **140** in the cluster lithography track system **100**, transfer the wafer W to the scanner **150**, and match vacuum degrees of the transfer module **140** and the scanner **150**.

[0051] The transfer module **140** may maintain a normal pressure or vacuum state, and since work is carried out in the vacuum state of the scanner **150**, a separate load lock that may adjust a vacuum degree of the transfer module **140** to match the vacuum degree of the scanner **150** is required. The first interface box **160**, which may control normal pressure or vacuum, performs the role of a load lock.

[0052] Since the first interface box **160** directly connects the scanner to a dry lithography facility, all photolithography processes may be performed as dry photolithography processes. Through the dry photolithographic process, patterns on semiconductor chips may become reliably further refined.

[0053] In addition, in the lithography track system **100** in which the scanner **150** is in-line, the exposure process may be performed continuously without moving to an external scanner, so a contamination problem of the wafer, a front-opening unified pod (FOUP), and the transfer module due to metal reaction by-products in the exposure process may be resolved. Since the cleaning process to remove contamination from the wafer is also reduced, the cost of installing a separate cleaning device may be reduced and process time and productivity may be improved.

[0054] Before introducing the wafer that has undergone the dry photography process into the scanner **150**, a wafer handler operating under normal pressure conditions to move the wafer to the scanner **150** may be removed and the wafer may be directly moved to the scanner **150** through the transfer module **140** that passes through the first interface box **160** capable of vacuum adjustment, thereby eliminating vacuum degree matching delay for adjusting the vacuum degree at normal pressure.

[0055] A track-type lithography track system **200** of FIG. **2** includes a plurality of process modules **220**, a transfer module **240**, a scanner **250**, and a first interface box **260**.

[0056] The plurality of process modules **220** includes process modules **222**, **224**, . . . that perform each semiconductor process for a semiconductor photolithography process.

[0057] The plurality of process modules **220** performing the photolithography process of the wafer W may include a coating process module, a baking process module, and a dry development

- module, like the process module of the cluster-type lithography track system **100** of the example embodiment of FIG. **1**.
- [0058] The location or number of the process modules **222** and **224** may be arbitrarily changed depending on selection.
- [0059] Descriptions of process modules common to FIG. **1** may be omitted in the interest of brevity.
- [0060] One end of the track-type lithography track system **200** is connected to an EFEM **202**, and the process modules **220** are arranged on both or opposite sides based on the transfer module **240** transferring the wafer W.
- [0061] Like the transfer module **140** of the cluster-type lithography track system **100** of FIG. **1**, the transfer module **240** includes a vacuum transfer robot (or a vacuum transport module) **245** for transferring the wafer and a track **242** on which the vacuum transfer robot **245** may move.
- [0062] The scanner **250** may be located at one end of the transfer module **240**, and the wafer is moved to the scanner **250** for an exposure process through the transfer module **240**. The wafer that has completely undergone the exposure process may be transferred from the scanner **250** to the process module **220**.
- [0063] FIG. **3** is a schematic diagram illustrating portion A of FIG. **1** according to example embodiments, while FIG. **4** is a schematic diagram illustrating portion A' of FIG. **2** according to example embodiments.
- [0064] FIGS. **3** and **4** illustrate the first interface boxes **160** and **260** of the cluster-type lithography track system and the track-type lithography track system, respectively.
- [0065] Referring to FIGS. **3** and **4**, the first interface boxes **160** and **260** include at least one of a baking process module **168**, an alignment module **164**, a buffer module **166**, and a cleaning module **162**.
- [0066] The baking process module **168** may perform soft baking and post-exposure baking (PEB) required before and after exposure performed by the scanner **150**.
- [0067] The alignment module **164** may control the temperature of the wafer W before the wafer is introduced into the scanner and may also remove outgassing of metal-based reaction by-products occurring due to baking of the wafer W.
- [0068] The buffer module **166** may serve to remove moisture from the first interface boxes **160** and **260** against the risk of critical dimension drift occurring within the wafer during an idle time before and after exposure in the scanners **150** and **250**.
- [0069] The cleaning module **162** may clean the wafer W in a wet or dry manner to perform bevel edge and back cleaning.
- [0070] Within the first interface boxes **160** and **260**, the transfer module **140** or **240** moves the wafer W with the scanners **150** and **250**. A vacuum wafer handler **254** for receiving the wafer W in a vacuum state from the transfer module may be installed in the scanner **250**.
- [0071] Although the scanner wafer W is cleaned in the cleaning module **162**, the inside of the transfer module **140** or **240** itself may be cleaned by connecting the transfer module **140** or **240** to a plasma device to prevent a space within the first interface boxes **160** and **260** from being contaminated due to metal outgassing or contamination of the wafer W during the process.
- [0072] Within the first interface boxes **160** and **260**, the transfer module **140** or **240** may be coupled to the plasma device.
- [0073] The plasma device may be a direct plasma system or a remote plasma system and clean the inside of the transfer module **140** or **240** in a vacuum state against a problem in which contaminants may be introduced into the process module **120** or **220** of the photolithography, as well as to the scanners **150** and **250**.
- [0074] As described above, the first interface boxes **160** and **260** may be equipped with functional process modules capable of performing a necessary process before and after the exposure process, thereby timely performing the necessary processes before and after scanning to prevent

contamination of the semiconductor wafer or additional problems that may arise, such as drift of a critical dimension.

[0075] FIG. **5** is a schematic enlarged view illustrating portion B of FIG. **1** according to example embodiments, and FIG. **6** is a schematic enlarged view illustrating portion B' of FIG. **2** according to example embodiments. In addition, FIG. **7** is a schematic enlarged view illustrating portion B' of FIG. **2** according to other example embodiments.

[0076] Referring to FIGS. **5** and **6**, second interface boxes **180** and **280** of a cluster-type lithography track system and a track-type lithography track system, respectively, are illustrated. [0077] Still referring to FIGS. **5** and **6**, the second interface boxes **180** and **280** receive wafers from the transfer modules **140** and **240** between the process modules **120** and **220**.

[0078] The second interface boxes **180** and **280** include wafer-in-chambers **182** and **282**, wafer-out-chambers **184** and **284**, and robot arms **185** and **285**.

[0079] The wafer-in-chambers **182** and **282** are chambers disposed in a path through which the wafer W is introduced from the transfer modules **140** and **240** to the processing chambers **120** and **220** based on the second interface boxes **180** and **280**. In addition, the wafer-out-chambers **184** and **284** are chambers disposed in a path through which the wafer W, on which the semiconductor process has been performed, is discharged from the processing chambers **120** and **220** to the transfer modules **140** and **240** based on the second interface boxes **180** and **280**.

[0080] The robot arms **185** and **285** are between the wafer-in-chambers **182** and **282** and the wafer-out-chambers **184** and **284** and the process modules **120** and **220**. The robot arms **185** and **285** transfer the wafer W from the wafer-in-chambers **182** and **282** to the process modules **120** and **220** and from the process modules **120** and **220** to the wafer-out-chambers **184** and **284**.

[0081] The second interface boxes **180** and **280** manage spaces of the wafer-in-chambers **182** and **282** and the wafer-out-chambers **184** and **284** separately to reduce the possibility of metal contamination of the wafer W, thereby improving yield.

[0082] Referring to FIG. **7**, the wafer-out-chambers **184** and **284** may include a cleaning module. As the process progresses in the processor module, contaminated wafers may be cleaned. At this time, the wafer-out-chambers **184** and **284** may be coupled to a plasma device, such as a remote plasma source (RPS) to remove contamination of the wafer-out-chambers **184** and **284**.

[0083] FIG. **8** is a schematic diagram of a wafer being transferred to a process module in a track-type lithography track system according to example embodiments of the present inventive concept. [0084] Referring to FIG. **8**, it can be seen that vacuum degree matching between the wafer-in-chamber **282** and the process module **222** is independent of vacuum degree matching between the wafer-in-chamber **282** and the transfer module **240**.

[0085] In FIG. **8**, a, b, and c show differences in pressure. For example, a is normal pressure, b is a pressure at which normal pressure and vacuum intersect, and c is a pressure in a vacuum state. Pressure may change depending on the type of process or a transfer method.

[0086] Various process modules **222**, **224**, **226**, and **228** and the transfer module **240** of photolithography should maintain a certain vacuum degree, and each of the process modules **222**, **224**, **226**, and **228** may have a different vacuum degree.

[0087] The wafer may be transferred only when the process modules **222**, **224**, **226**, and **228** and the transfer module **240** have the same vacuum degree. The second interface box **280** is located between the process modules **222**, **224**, **226**, and **228** and the transfer module **240**, and when the vacuum degrees of the wafer-in-chamber **282** and the transfer module **240** match, the wafer is first transferred to the wafer-in-chamber **282** of the process module **222**.

[0088] The vacuum degree matching between the first process module **222** and the wafer-in-chamber **282** is performed independently from the vacuum degree matching between the wafer-in-chamber **282** and the transfer module **240**. When the vacuum degrees of the first process module **222** and the wafer-in-chamber **282** match, the wafer in the wafer-in-chamber **282** is transferred to the first process module **222**. After a semiconductor process is performed in the first process

module 222, the wafer is transferred to the wafer-out-chamber 284.

[0089] Vacuum degree matching with the transfer module **240** is prepared so that the wafer is transferred from the wafer-out-chamber **284** to other process modules **224**, **226**, and **228** and a subsequent photolithography semiconductor process is performed. The wafer-out-chamber **284** may be equipped with a cleaning unit or connected to a remote plasma source to clean the wafer contaminated in the first process module **222**. The wafer cleaned in the wafer-out-chamber **284** does not spread contamination to the transfer module **240**.

[0090] Like the first process module, the other process modules **224**, **226**, and **228** transfer wafers and perform respective semiconductor processes.

[0091] In this manner, since the second interface box **280** including the wafer-in-chamber **282** and the wafer-out-chamber **284** is located between the process modules **222**, **224**, and **226** and the transfer module **240**, vacuum degree matching between the wafer-in-chamber **282** and the process modules **222**, **224**, and **226** may be performed independently of vacuum degree matching between the wafer-in-chamber and the transfer module, and thus, the process modules of the track system may operate independently of each other even without a vacuum degree matching operation with the transfer module, thereby significantly improving a work speed.

[0092] According to the lithography track system of example embodiments of the present inventive concept, which is a dry photolithography track system, the photolithography process may be continuously performed without moving a wafer to an external scanner for the exposure process and all photolithography processes may be performed as dry photolithography processes. Through the dry photolithographic process, patterns on semiconductor chips may be reliably further refined. [0093] In addition, in the lithography track system with the in-line scanner, the exposure process may be performed continuously without moving a wafer to an external scanner, thereby eliminating the problem of contamination of the wafer, FOUP, and transfer module due to metal reaction byproducts in the exposure process. Since the cleaning process to remove contamination is also reduced, the cost of installing a separate cleaning device may be reduced and process time and productivity may be improved.

[0094] Before introducing a wafer that has undergone a dry photography process into the scanner, a wafer handler operating under normal pressure conditions to move the wafer to the scanner may be removed and the wafer may be moved directly to the scanner through a transfer module that passes through the first interface box capable of vacuum adjustment, thereby eliminating vacuum degree matching delay for adjusting the vacuum degree at normal pressure.

[0095] The first interface box may be equipped with process modules capable of performing a necessary process before and after the exposure process, thereby timely performing the necessary processes before and after scanning to prevent contamination of the semiconductor wafer or additional problems that may arise, such as drift of a critical dimension.

[0096] In addition, since the second interface box, which is disposed between the process module and the transfer module, matches in the vacuum degree with the transfer module, and also matches in the vacuum degree with the process module, separate from the transfer module, is provided, the process modules of the track system may operate independently of each other even without a vacuum degree matching operation with the transfer module, thereby significantly improving a work speed.

[0097] While example embodiments have been shown and described above, it will be apparent to those skilled in the art that modifications and variations could be made without departing from the scope of the present inventive concept as defined by the appended claims.

## **Claims**

**1**. A lithography track system comprising: a plurality of process modules each configured to perform a photolithography process on a wafer; a transfer module configured to transfer the wafer

between the plurality of process modules; a scanner at one end of the transfer module and configured to expose a photoresist material on the wafer; and a first interface box sharing the transfer module and configured to transfer the wafer to the scanner and to match vacuum degrees of the transfer module and the scanner.

- **2**. The lithography track system of claim 1, wherein the plurality of process modules include: a coating process module configured to coat the wafer with photoresist; a baking process module configured to bake the coated or exposed wafer; and a dry development module configured to dryremove the exposed wafer or a pattern thereon.
- **3.** The lithography track system of claim 1, wherein the first interface box includes at least one of a baking process module, an alignment module, a buffer module, and a cleaning module.
- **4.** The lithography track system of claim 1, wherein the transfer module is coupled to a plasma device within the first interface box.
- **5.** The lithography track system of claim 1, wherein a second interface box configured to move the wafer to and from the transfer module is included between at least one of the plurality of process modules and the transfer module.
- **6**. The lithography track system of claim 5, wherein the second interface box includes: a wafer-inchamber configured to separately match a vacuum degree with the transfer module or the process module; a wafer-out-chamber configured to transfer the wafer from the process module to the transfer module; and a robot arm between the wafer-in-chamber and the wafer-out-chamber and the process module, and configured to transfer the wafer from the wafer-in-chamber to the process module and from the process module to the wafer-out-chamber.
- 7. The lithography track system of claim 6, wherein vacuum degree matching between the wafer-in chamber and the process module is performed independently of vacuum degree matching between the wafer-in chamber and the transfer module.
- **8**. The lithography track system of claim 6, wherein the wafer-out-chamber includes a cleaning module.
- **9.** The lithography track system of claim 1, wherein an arrangement of the process module and the transfer module is a cluster-type.
- **10**. The lithography track system of claim 1, wherein an arrangement of the process module and the transfer module is a track-type.
- 11. A lithography track system, in which a wafer is sequentially transferred to a plurality of process modules and processed sequentially or simultaneously in the plurality of process modules, the lithography track system comprising: a transfer module configured to transfer the wafer between the plurality of process modules, wherein the plurality of process modules include: a coating process module configured to dry-coat the wafer with photoresist; a scanner configured to expose the coated wafer to electromagnetic radiation; a baking process module configured to dry-bake the coated or exposed wafer; and a dry development module configured to dry-remove the exposed wafer or a pattern thereon, wherein a first interface box configured to match a vacuum degree with the scanner is at an introduction side of the scanner.
- **12**. The lithography track system of claim 11, wherein the first interface box is formed continuously with the transfer module and includes at least one of a baking process module, an alignment module, a buffer module, and a cleaning module.
- **13**. The lithography track system of claim 11, wherein the transfer module is coupled to a plasma device within the first interface box.
- **14.** The lithography track system of claim 11, wherein the plurality of process modules include a second interface box configured to move the wafer with the transfer module, and the second interface box includes: a wafer-in-chamber configured to separately match a vacuum degree with the transfer module or the process module; a wafer-out-chamber configured to transfer the wafer from the process module to the transfer module; and a robot arm between the wafer-in-chamber and the wafer-out-chamber and the process module, and configured to transfer the wafer from the

wafer-in-chamber to the process module and from the process module to the wafer-out-chamber.

- **15**. The lithography track system of claim 14, wherein vacuum degree matching between the waferin chamber and the process module is performed independently of vacuum degree matching between the wafer-in chamber and the transfer module.
- **16**. A lithography track system comprising: an equipment front-end module configured to supply a wafer; a plurality of process modules configured to sequentially or simultaneously process the wafer; a transfer module having a first end connected to the equipment front-end module and configured to transfer the wafer; and a second interface box configured to move the wafer to and from the transfer module between at least one of the plurality of process modules and the transfer module.
- 17. The lithography track system of claim 16, wherein the second interface box includes: a wafer-in-chamber configured to separately match a vacuum degree with the transfer module or the process module; a wafer-out-chamber configured to transfer the wafer from the process module to the transfer module; and a robot arm between the wafer-in-chamber and the wafer-out-chamber and the process module, and configured to transfer the wafer from the wafer-in-chamber to the process module and from the process module to the wafer-out-chamber.
- **18.** The lithography track system of claim 16, further comprising: a scanner connected to a second end of the transfer module that is opposite the first end of the transfer module; and a first interface box in-line with the transfer module adjacent the scanner and configured to match vacuum degrees of the transfer module and the scanner.
- **19**. The lithography track system of claim 18, wherein a moving rail of the transfer module is connected to the scanner, a plurality of process modules are arranged on opposing sides of the transfer module, and the plurality of process modules include: a coating process module configured to coat the wafer with photoresist; a baking process module configured to bake the coated or exposed wafer; and a dry development module configured to dry-remove the exposed wafer or a pattern thereon.
- **20**. The lithography track system of claim 18, wherein the first interface box includes at least one of a baking process module, an alignment module, a buffer module, and a cleaning module.